NSN 5961-01-095-1213

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-095-1213 **Inclosure Material:** Metal **Overall Length:** 1.266 inches **Overall Height:** Between 0.250 inches and 0.340 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case and burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to emitter voltage/static/base open and 60.0 collector to base voltage, dc and 5.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 8.00 milliamperes source cutoff current and 50.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector preset **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No